

- Ideal for European 433.90 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Surface-Mount Ceramic Case with 21 mm² Footprint

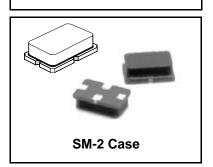
The RO2160A is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount, ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 433.90 MHz. This SAW is designed for AM transmitters in automotive-keyless-entry applications.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+5	dBm
DC Voltage Between Terminals	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature	+250	°C

RO2160A

433.90 MHz SAW Resonator



Electrical Characteristics

Cha	aracteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency at +25 °C	Absolute Frequency	f _C	2 2 4 5		433.90		MHz
	Tolerance from 433.90 MHz	Δf_{C}	2, 3, 4, 5			±50	kHz
Insertion Loss		IL	2, 5, 6		1.1	2.0	dB
Quality Factor	Unloaded Q	Q _U	5 6 7		14,300		
	50 Ω Loaded Q	Q_L	5, 6, 7		1,700		
Temperature Stability	Turnover Temperature	T _O		10	25	40	°C
	Turnover Frequency	f _O	6, 7, 8		f _C		kHz
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	fA	1			±50	ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			ΜΩ
RF Equivalent RLC Model	Motional Resistance	R_{M}			13	26	Ω
	Motional Inductance	L _M	5, 6, 7, 9		69.4594		μH
	Motional Capacitance	C _M			1.93682		fF
	Transducer Static Capacitance	C _P	5, 6, 7, 9	1.5	1.8	2.1	pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		75		nΗ
Lid Symbolization		253					

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CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

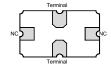
- 1. Lifetime (10 year) frequency aging.
- 2. The center frequency, f_C , is measured at the minimum insertion loss point, IL_{MIN} , with the resonator in the 50 Ω test system (VSWR \leq 1.2:1). The shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_C .
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5. Unless noted otherwise, case temperature $T_C = +25^{\circ}C \pm 2^{\circ}C$ for all specifications
- 6. The design, manufacturing process, and specifications of this device are subject to change without notice.
- 7. Derived mathematically from one or more of the following directly measured parameters: f_C , IL, 3 dB bandwidth, f_C versus T_C , and C_O .
- Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be cal-

- culated from: $f = f_O [1 FTC (T_O T_C)^2]$.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can be calculated as: C_P ≈ C_O 0.05 pF.

SAW Resonator

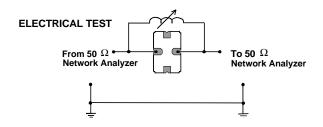
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit

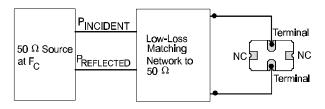


Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_{O} , at F_{C} .

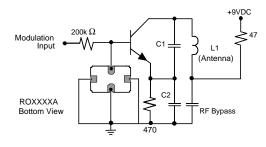


POWER TEST

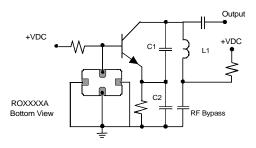


CW RF Power Dissipation = P_{INCIDENT} - P_{REFLECTED} **Typical Application Circuits**

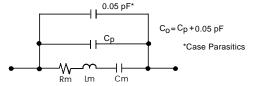
Typical Low-Power Transmitter Application



Typical Local Oscillator Application

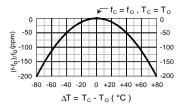


Equivalent LC Model



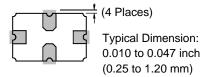
Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



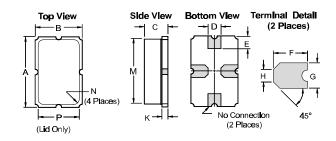
Typical Circuit Board Land Pattern

The circuit board land pattern shown below is one possible design. The optimum land pattern is dependent on the circuit board assembly process which varies by manufacturer. The distance between adjacent land edges should be at a maximum to minimize parasitic capacitance. Trace lengths from terminal lands to other components should be short and wide to minimize parasitic series inductances.



Case Design

The case material is black alumina with contrasting symbolization. All pads are nominally centered with respect to the base and consist of 60 to 100 microinches (min) electroless gold on 50 microinches (min) electroless nickel.



Dimensions	Millimeters		Inches		
	Min	Max	Min	Max	
Α		5.97		0.235	
В		3.94		0.155	
С		2.16		0.085	
D	0.94	1.10	0.037	0.043	
E	0.83	1.20	0.033	0.047	
F	1.16	1.53	0.046	0.060	
G	0.94	1.10	0.037	0.043	
Н	0.43	0.59	0.017	0.023	
K	0.43	0.59	0.17	0.023	
M		5.31		0.209	
N	0.38	0.64	0.015	0.025	
Р		3.28		0.129	